Preferred Device

Sensitive Gate Triacs

Silicon Bidirectional Thyristors

Designed for industrial and consumer applications for full wave control of ac loads such as appliance controls, heater controls, motor controls, and other power switching applications.

- Sensitive Gate Allows Triggering by Microcontrollers and other Logic Circuits
- Blocking Voltage to 800 Volts
- On-State Current Rating of 12 Amperes RMS at 70°C
- High Surge Current Capability 90 Amperes
- Rugged, Economical TO220AB Package
- Glass Passivated Junctions for Reliability and Uniformity
- Minimum and Maximum Values of I_{GT}, V_{GT} and I_H Specified for Ease of Design
- High Commutating di/dt 8.0 A/ms Minimum at 110°C
- Immunity to dV/dt 15 V/μsec Minimum at 110°C
- Operational in Three Quadrants: Q1, Q2, and Q3
- Device Marking: Logo, Device Type, e.g., MAC12SM, Date Code

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Peak Repetitive Off–State Voltage ⁽¹⁾ (T _J = -40 to 110°C, Sine Wave, 50 to 60 Hz, Gate Open)	V _{DRM,} V _{RRM}		Volts
MAC12SM MAC12SN		600 800	
On-State RMS Current (All Conduction Angles; T _C = 70°C)	I _{T(RMS)}	12	Amps
Peak Non-Repetitive Surge Current (One Full Cycle Sine Wave, 60 Hz, T _J = 110°C)	ITSM	90	Amps
Circuit Fusing Consideration (t = 8.33 ms)	I ² t	33	A ² sec
Peak Gate Power (Pulse Width = 1.0 μsec, T _C = 70°C)	PGM	16	Watts
Average Gate Power (t = 8.3 msec, T _C = 70°C)	PG(AV)	0.35	Watt
Operating Junction Temperature Range	TJ	-40 to 110	°C
Storage Temperature Range	T _{stg}	-40 to 150	°C

⁽¹⁾ VDRM and VRRM for all types can be applied on a continuous basis. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

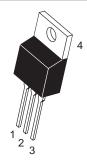


ON Semiconductor

http://onsemi.com

TRIACS 12 AMPERES RMS 600 thru 800 VOLTS





TO-220AB CASE 221A STYLE 4

PIN ASSIGNMENT			
1	Main Terminal 1		
2	Main Terminal 2		
3	Gate		
4	Main Terminal 2		

ORDERING INFORMATION

Device	Package	Shipping
MAC12SM	TO220AB	50 Units/Rail
MAC12SN	TO220AB	50 Units/Rail

Preferred devices are recommended choices for future use and best overall value.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Thermal Resistance — Junction to Case — Junction to Ambient	R _{ÐJC} R _{ÐJA}	2.2 62.5	°C/W
Maximum Lead Temperature for Soldering Purposes 1/8" from Case for 10 Seconds	TL	260	°C

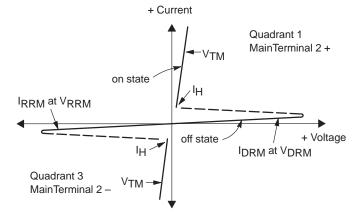
ELECTRICAL CHARACTERISTICS (T_{.1} = 25°C unless otherwise noted; Electricals apply in both directions)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS	•				
Peak Repetitive Blocking Current (V_D = Rated V_{DRM} , V_{RRM} ; Gate Open) T_J = 25°C T_J = 110°C	I _{DRM} , I _{RRM}	_ _	_ _	0.01 2.0	mA
ON CHARACTERISTICS					
Peak On-State Voltage(1) ($I_{TM} = \pm 17 \text{ A}$)	VTM	_	_	1.85	V
Gate Trigger Current (Continuous dc) (V _D = 12 V, R _L = 100 Ω) MT2(+), G(+) MT2(+), G(-) MT2(-), G(-)	^I GT	0.8 0.8 0.8	1.5 2.5 2.7	5.0 5.0 5.0	mA
Holding Current (V _D = 12 V, Gate Open, Initiating Current = ±200 mA)		1.0	2.5	10	mA
Latching Current ($V_D = 12 \text{ V}, I_G = 5 \text{ mA}$) MT2(+), G(+) MT2(+), G(-) MT2(-), G(-)	IL	2.0 2.0 2.0	3.0 5.0 3.0	15 20 15	mA
Gate Trigger Voltage (Continuous dc) (V_D = 12 V , R_L = 100 Ω) MT2(+), G(+) MT2(+), G(-) MT2(-), G(-)	VGT	0.45 0.45 0.45	0.68 0.62 0.67	1.5 1.5 1.5	V
DYNAMIC CHARACTERISTICS					
Critical Rate of Change of Commutating Current (V _D = 400 V, I _{TM} = 3.5 A, Commutating dV/dt = 10 V/ μ s, Gate Open, T _J = 110°C, f = 500 Hz, Snubber: Cs = 0.01 μ f, Rs = 15 Ω)		8.0	10	_	A/ms
Critical Rate of Rise of Off-State Voltage ($V_D = 67\% \ V_{DRM}$, Exponential Waveform, $R_{GK} = 1 \ K\Omega$, $T_J = 110^{\circ}C$)	dV/dt	15	40	_	V/µs
Repetitive Critical Rate of Rise of On-State Current IPK = 50 A; PW = 40 μsec; diG/dt = 1 A/μsec; Igt = 100 mA; f = 60 Hz	di/dt	_	_	10	A/μs

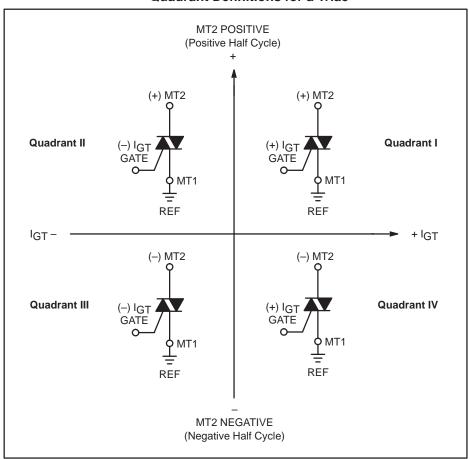
⁽¹⁾ Pulse Test: Pulse Width ≤ 2.0 ms, Duty Cycle ≤ 2%.

Voltage Current Characteristic of Triacs (Bidirectional Device)

Symbol	Parameter
VDRM	Peak Repetitive Forward Off State Voltage
IDRM	Peak Forward Blocking Current
VRRM	Peak Repetitive Reverse Off State Voltage
IRRM	Peak Reverse Blocking Current
V _{TM}	Maximum On State Voltage
lΗ	Holding Current



Quadrant Definitions for a Triac



All polarities are referenced to MT1.

With in-phase signals (using standard AC lines) quadrants I and III are used.

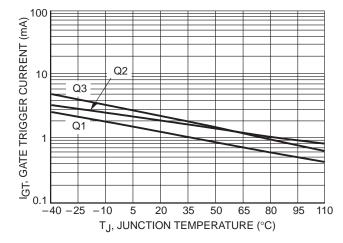


Figure 1. Typical Gate Trigger Current versus Junction Temperature

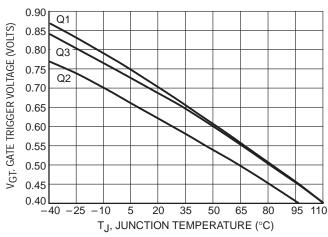


Figure 2. Typical Gate Trigger Voltage versus Junction Temperature

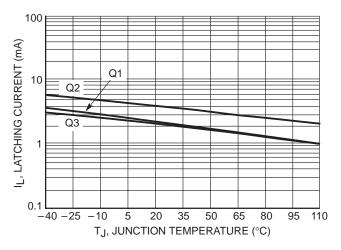


Figure 3. Typical Latching Current versus Junction Temperature

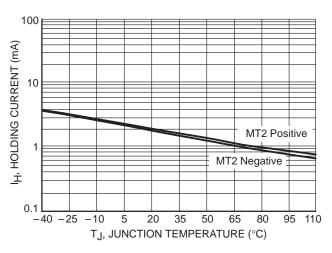


Figure 4. Typical Holding Current versus Junction Temperature

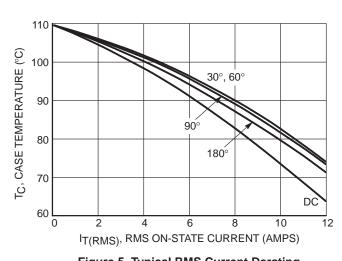


Figure 5. Typical RMS Current Derating

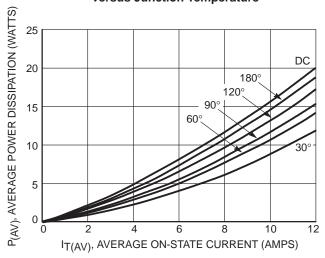


Figure 6. On-State Power Dissipation

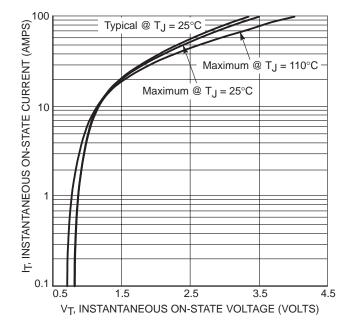


Figure 7. Typical On-State Characteristics

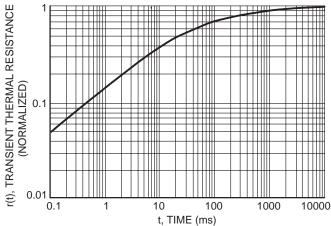
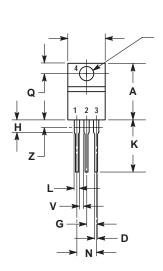
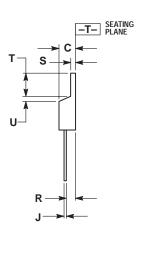


Figure 8. Typical Thermal Response

PACKAGE DIMENSIONS

TO-220AB CASE 221A-09 ISSUE Z





- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.570	0.620	14.48	15.75
В	0.380	0.405	9.66	10.28
С	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.147	3.61	3.73
G	0.095	0.105	2.42	2.66
Н	0.110	0.155	2.80	3.93
J	0.018	0.025	0.46	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
V	0.045		1.15	
Z		0.080		2.04

- STYLE 4:
 PIN 1. MAIN TERMINAL 1
 2. MAIN TERMINAL 2
 3. GATE
 4. MAIN TERMINAL 2



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